Optimization of Milling Duration of SBT Nanocrystalline Ferroelectric Ceramic

A Dissertation Submitted towards the Partial Fulfilment of Award of Degree of

MASTER OF TECHNOLOGY In NANO SCIENCE AND TECHNOLOGY

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CERTIFICATE

This is to certify that the dissertation on the topic entitled **"Optimization of Milling Duration of SBT Nanocrystalline Ferroelectric Ceramic"** has completed the work by Mr. Manish Dwivedi (2K10/NST/09) carried out under my supervision in partial fulfilment of the requirement towards the degree of Master of Technology (M.Tech.) in Nano Science and Technology of Department of Applied Physics, Delhi Technological University, New Delhi.

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ACKNOWLEDGEMENT

I am deeply grateful to **Dr. R .K. SINHA**, Head of Department (Applied Physics), Delhi Technological University for his support and encouragement in carrying out this project work in the Department of Applied Physics.

I wish to express my deep sense of gratitude to my project guide, **Dr. Mohan Singh Mehata**, of Department of Applied Physics for his valuable guidance and suggestions at all stages of this work. I am also very grateful to **Ms. Sugandha Miglani**, Research Scholar of Department of Applied Physics for her help at the time of making sample and obtaining result and discussion, and her constructive criticism of this approach to the problems during the course of this work helped me to a great extent in bringing this work to its present state.

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ABSTRACT

Nanocrystalline ferroelectric ceramics are important electronic materials having a wide range of scientific and industrial applications such as high dielectric constant capacitors, piezoelectric transducers, pyroelectric sensors, non volatile ferroelectric random access memories, etc. It is well known that performance of any material is closely related to its synthesis process. The methods of synthesis of ferroelectric powders play a significant role in determining the microstructural, electrical and optical properties of these materials. In the present work, nanocrystalline specimens of Strontium Bismuth Tantalate (SBT) ferroelectric ceramics has been synthesized by two technique 1) Solid State reaction Method 2)Mechanical activation process using a high energy planetary ball mill. The powders has been milled for different milling durations (5, 10, 20 hours, etc.), keeping the milling speed fixed at 300 rpm. Microstructural characterizations were performed using X-ray diffraction, scanning electron microscopy. Detailed dielectric study as a function of temperature has been carried out. The observed results have been explained in terms of increased number of grain boundaries due to the reduction of granular size. In the present work, milling hours has been optimized to get enhanced microstructure and dielectric constant of the prepared specimen

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